

N-channel 60 V, 9.9 mΩ standard level MOSFET in LFPAK33 19 September 2016 Product data sheet

1. General description

Standard level N-channel MOSFET in an LFPAK33 (Power33) package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

2. Features and benefits

- Q101 Compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True standard level gate with $V_{GS(th)}$ rating of greater than 1 V at 175 °C

3. Applications

- 12 V automotive systems
- Motors, lamps and solenoid control
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	-	60	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	-	60	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	-	79	W
Static charact	eristics					
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 15 A; T _j = 25 °C; Fig. 11	-	8	9.9	mΩ
Dynamic char	acteristics					
Q _{GD}	gate-drain charge	$I_D = 15 \text{ A}; V_{DS} = 48 \text{ V}; V_{GS} = 10 \text{ V};$ $T_j = 25 \text{ °C}; Fig. 13; Fig. 14$	-	10.4	-	nC

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N-channel 60 V, 9.9 m Ω standard level MOSFET in LFPAK33

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	Source		D
2	S	Source		
3	S	Source		G-UFT 4
4	G	Gate		mbb076 S
mb	D	Mounting base; connected to drain	LFPAK33 (SOT1210)	

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
BUK7M9R9-60E	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 8 leads	SOT1210			

7. Marking

Table 4. Marking codes	
Type number	Marking code
BUK7M9R9-60E	79E960

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	60	V
V _{DGR}	drain-gate voltage	R _{GS} = 20 kΩ	-	60	V
V _{GS}	gate-source voltage	DC; T _j ≤ 175 °C	-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	79	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	60	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>	-	42	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^\circ C$; Fig. 3	-	240	А
T _{stg}	storage temperature		-55	175	°C

N-channel 60 V, 9.9 mΩ standard level MOSFET in LFPAK33

Symbol	Parameter	Conditions		Min	Max	Unit
Tj	junction temperature			-55	175	°C
Source-drai	in diode					
I _S	source current	T _{mb} = 25 °C		-	60	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^\circ C$		-	240	А
Avalanche	ruggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$I_D = 60 \text{ A}; V_{sup} \le 60 \text{ V}; \text{ R}_{GS} = 50 \Omega;$ V _{GS} = 10 V; T _{j(init)} = 25 °C; unclamped; Fig. 4	[1][2]	-	45.4	mJ

[1] Single-pulse avalanche rating limited by maximum junction temperature of 175 $^\circ$ C.

[2] Refer to application note AN10273 for further information.

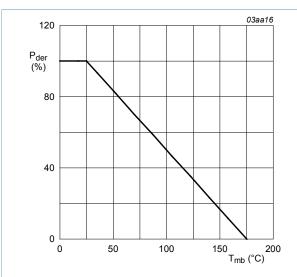
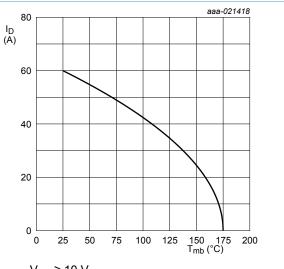


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

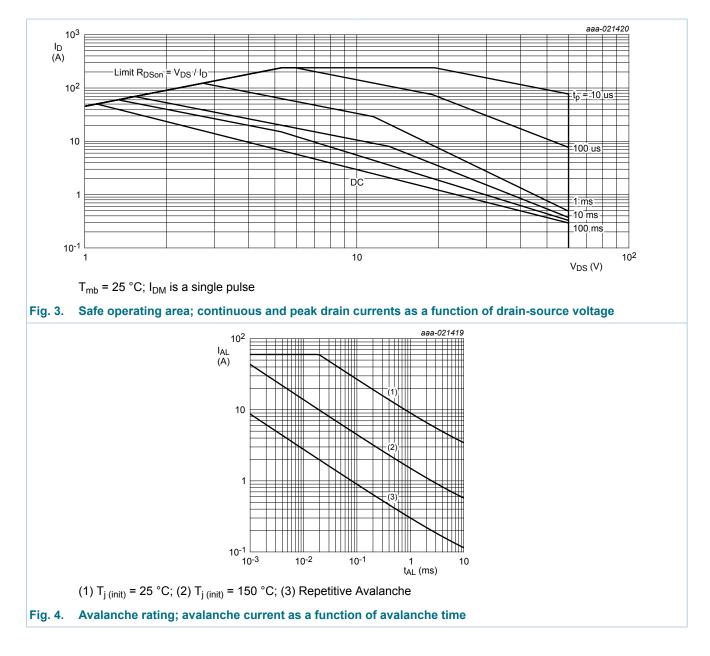


V_{GS} ≥ 10 V

Fig. 2. Continuous drain current as a function of mounting base temperature

$$I_D = 60A \times \sqrt{\frac{175^{\circ}C - T_{mb}}{150^{\circ}C}}$$
 for $T_{mb} \ge 25^{\circ}C$

N-channel 60 V, 9.9 m Ω standard level MOSFET in LFPAK33

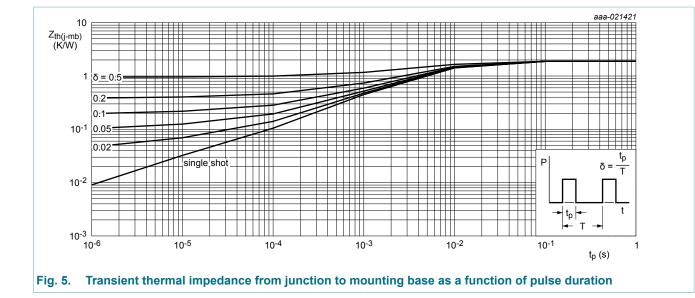


9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	1.58	1.89	K/W

BUK7M9R9-60E

N-channel 60 V, 9.9 mΩ standard level MOSFET in LFPAK33



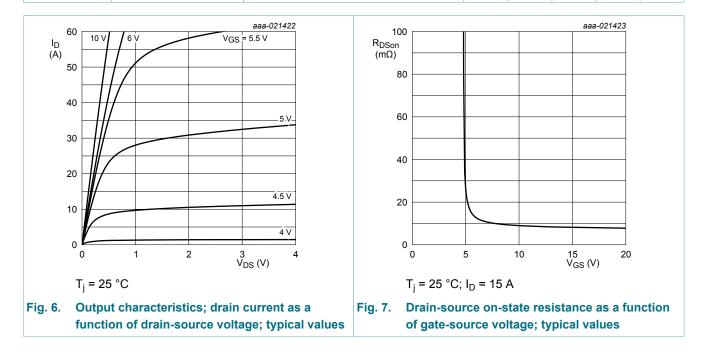
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Static chara	acteristics	· · · · ·					
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	60	-	-	V	
	breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	54	-	-	V	
V _{GS(th)}	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 25 °C; Fig. 9; Fig. 10	2.4	3	4	V	
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 9	-	-	4.5	V	
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ Fig. 9	1	-	-	V	
I _{DSS} drain leakage currer	drain leakage current	V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25 °C	-	0.01	1	μA	
			V_{DS} = 60 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA	
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA	
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 15 A; T _j = 25 °C; Fig. 11	-	8	9.9	mΩ	
			V _{GS} = 10 V; I _D = 15 A; T _j = 175 °C; Fig. 12	-	-	22	mΩ
Dynamic ch	naracteristics	· · · ·					
Q _{G(tot)}	total gate charge	I _D = 15 A; V _{DS} = 48 V; V _{GS} = 10 V;	-	30.1	-	nC	
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 13; Fig. 14</u>	-	7	-	nC	
Q _{GD}	gate-drain charge		-	10.4	-	nC	

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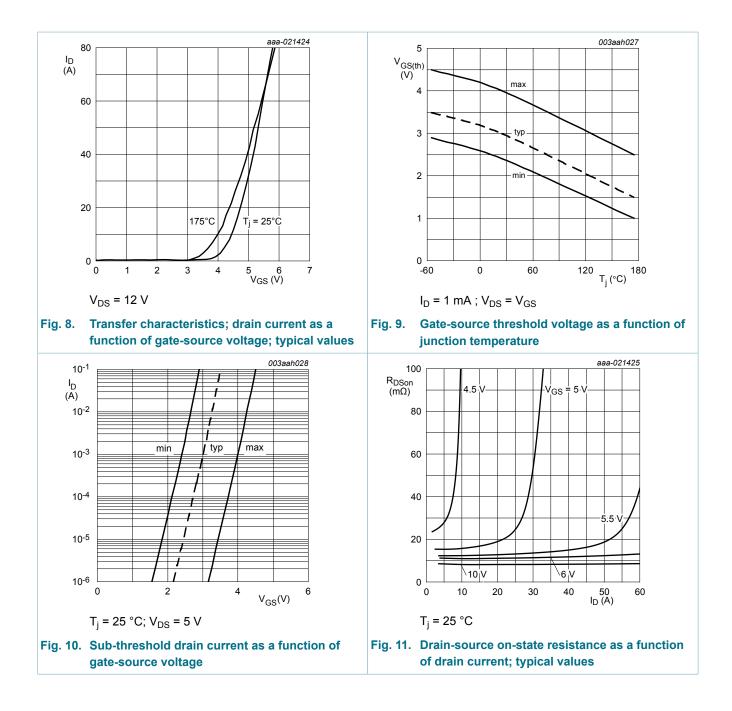
N-channel 60 V, 9.9 m Ω standard level MOSFET in LFPAK33

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{iss}	input capacitance	V_{DS} = 25 V; V_{GS} = 0 V; f = 1 MHz;	-	1509	2007	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 15</u>	 -	201	241	pF
C _{rss}	reverse transfer capacitance		-	127	174	pF
t _{d(on)}	turn-on delay time	V_{DS} = 45 V; R _L = 3 Ω; V _{GS} = 10 V; R _{G(ext)} = 5 Ω; T _j = 25 °C	-	7.1	-	ns
t _r	rise time		 -	11	-	ns
t _{d(off)}	turn-off delay time		-	21.9	-	ns
t _f	fall time		-	12.8	-	ns
Source-dra	ain diode	1				
V _{SD}	source-drain voltage	I_{S} = 15 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 16</u>	-	0.83	1.2	V
t _{rr}	reverse recovery time	I_{S} = 15 A; dI_{S}/dt = -100 A/µs; V_{GS} = 0 V;	-	21.4	-	ns
Q _r	recovered charge	V _{DS} = 25 V; T _j = 25 °C	 -	20.1	-	nC



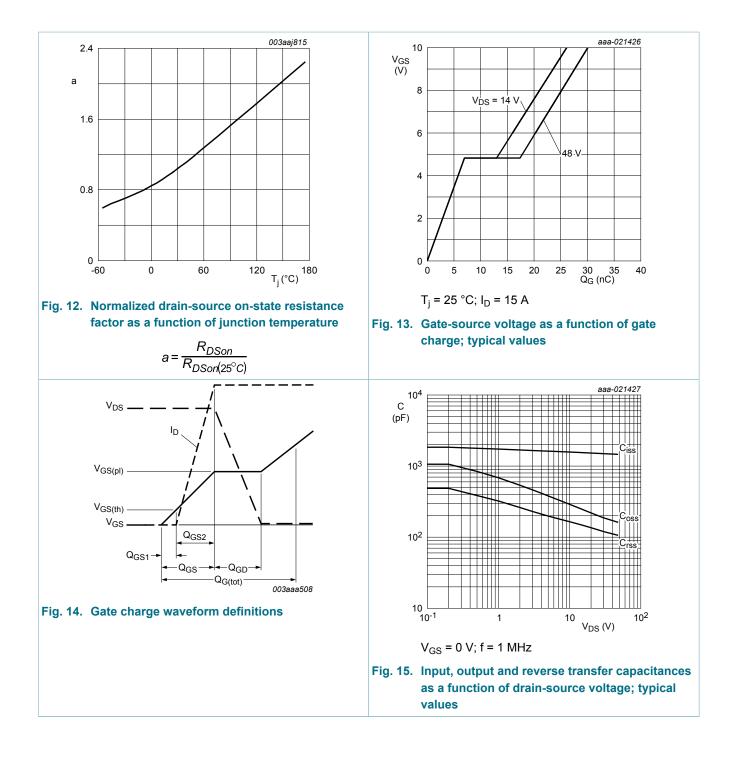
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N-channel 60 V, 9.9 m Ω standard level MOSFET in LFPAK33



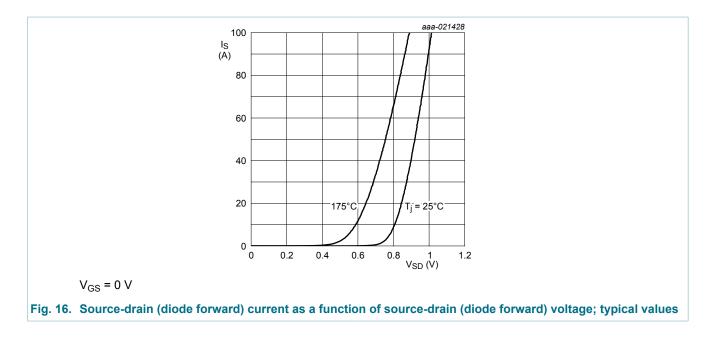
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N-channel 60 V, 9.9 m Ω standard level MOSFET in LFPAK33



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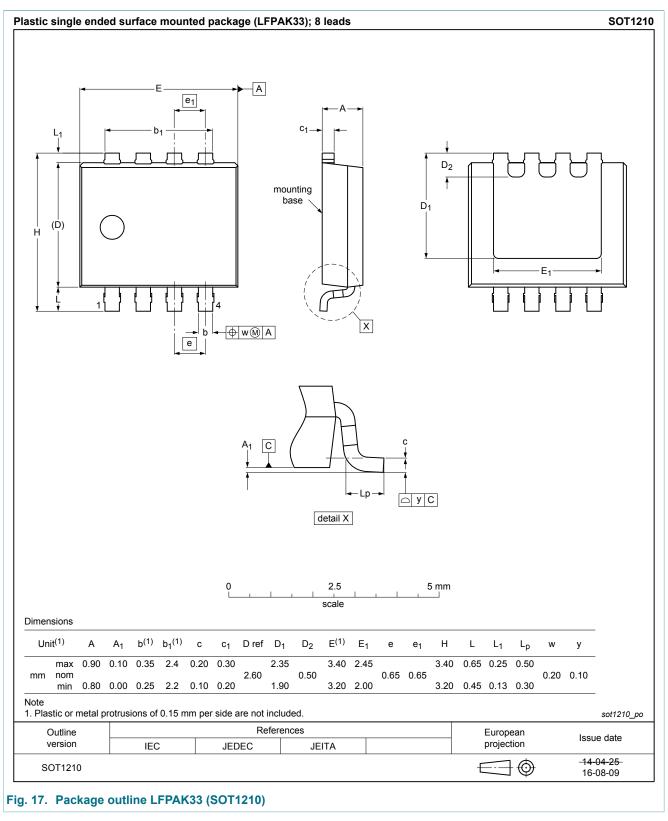


11. Application information

For guidance on how to use and understand this datasheet, please refer to application note <u>AN11158</u> "Understanding power MOSFET datasheet parameters".

N-channel 60 V, 9.9 mΩ standard level MOSFET in LFPAK33

12. Package outline



BUK7M9R9-60E

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N-channel 60 V, 9.9 m Ω standard level MOSFET in LFPAK33

13. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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N-channel 60 V, 9.9 m Ω standard level MOSFET in LFPAK33

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N-channel 60 V, 9.9 m Ω standard level MOSFET in LFPAK33

14. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Marking	2
8	Limiting values	2
9	Thermal characteristics	4
10	Characteristics	5
11	Application information	9
12	Package outline	10
13	Legal information	11
13.1	Data sheet status	11
13.2	Definitions	
13.2 13.3	Definitions Disclaimers	

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